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STGD10NC60S STGP10NC60S

10 A, 600 V fast IGBT

Features

- Optimized performance for medium operating frequencies up to 5 kHz in hard switching
- Low on-voltage drop (V_{CE(sat)})

Application

■ Motor drive

Description

This IGBT utilizes the advanced PowerMESH™ process resulting in an excellent trade-off between switching performance and low on-state behavior.

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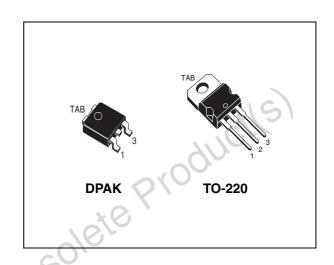


Figure 1. Internal schematic diagram

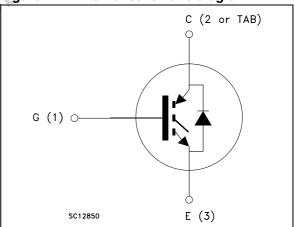


Table 1. Device summary

Order codes	Marking	Package	Packaging
STGD10NC60ST4	GD10NC60S	DPAK	Tape and reel
STGP10NC60S	GP10NC60S	TO-220	Tube

December 2010 Doc ID 15931 Rev 2 1/18

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1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Va	Unit	
Symbol	T didineter		TO-220	
V _{CES}	Collector-emitter voltage (V _{GE} = 0)	600		
I _C ⁽¹⁾	Continuous collector current at T _C = 25°C	18	21	Α
I _C ⁽¹⁾	Continuous collector current at T _C = 100°C	10	11	Α
I _{CL} (2)	Turn-off latching current	1	4 (0	Α
I _{CP} ⁽³⁾	Pulsed collector current	sed collector current 25		Α
V_{GE}	Gate-emitter voltage	±2	20	V
P _{TOT}	Total dissipation at T _C = 25 °C	60	62.5	W
T _j	Operating junction temperature	-55 to	150	°C

1. Calculated according to the iterative formula:

$$I_{C}(T_{C}) = \frac{T_{j(max)} - T_{C}}{R_{thj-c} \times V_{CE(sat)(max)}(T_{j(max)}, I_{C}(T_{C}))}$$

- 2. V_{clamp} = 80%,(V_{CES}), T_j =150 °C, R_G = 10 Ω , V_{GE} = 15 V
- 3. Pulse width limited by maximum junction temperature and turn-off within RBSOA

Table 3. Thermal data

Symbol	Parameter	Va	Unit	
Symbol	Farameter	DPAK	TO-220	Oilit
R _{thJC}	Thermal resistance junction-case	2.08	2	°C/W
R _{thJA}	Thermal resistance junction-ambient	100	62.5	°C/W

2 Electrical characteristics

 $T_J = 25~^{\circ}C$ unless otherwise specified.

Table 4. Static

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)CES}	Collector-emitter breakdown voltage (V _{GE} = 0)	I _C = 1 mA	600			V
V _{CE(sat)}	Collector-emitter saturation voltage	V _{GE} = 15 V, I _C = 5 A V _{GE} = 15 V, I _C = 5 A, T _J = 125 °C		1.45 1.45	1.65	V V
V _{GE(th)}	Gate threshold voltage	$V_{CE} = V_{GE}, I_{C} = 250 \mu A$	3.75		5.75	٧
I _{CES}	Collector cut-off current $(V_{GE}=0)$	V _{CE} = 600 V V _{CE} =600 V, T _J =125 °C	7.	JC	150 1	μA mA
I _{GES}	Gate-emitter leakage (V _{CE} =0)	V _{GE} = ±20 V	0		±100	nA
9 _{fs}	Forward transconductance	$V_{CE} = 15 V_{,} I_{C} = 5 A$		3.5		S

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
C _{ies} C _{oes} C _{res}	Input capacitance Output capacitance Reverse transfer capacitance	$V_{CE} = 25 \text{ V, f} = 1 \text{ MHz, V}_{GE} = 0$	-	365 44 8	1	pF pF pF
$egin{array}{c} Q_{ m g} \ Q_{ m gc} \end{array}$	Total gate charge Gate-emitter charge Gate-collector charge	$V_{CE} = 480 \text{ V, } I_{C} = 5 \text{ A,}$ $V_{GE} = 15 \text{ V}$ Figure 16	-	18 8 3.5	1	o o o

Table 6. Switching on/off (inductive load)

	Table 6.	Switching on/on (inductive load)					
	Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Opsole	t _{d(on)} t _r (di/dt) _{on}	Turn-on delay time Current rise time Turn-on current slope	V_{CC} = 390 V, I_{C} = 5 A R_{G} = 10 Ω , V_{GE} = 15 V, Figure 17	-	19 4 1330	-	ns ns A/µs
0	t _{d(on)} t _r (di/dt) _{on}	Turn-on delay time Current rise time Turn-on current slope	$V_{CC} = 390 \text{ V}, I_{C} = 5 \text{ A}$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V},$ $T_{J} = 125^{\circ}\text{C}$ Figure 17	-	18 4.5 1000	-	ns ns A/µs
$\begin{array}{ccc} & t_r(V_{off}) & \text{Off voltage rise time} \\ & t_d(_{off}) & \text{Turn-off delay time} \\ & t_f & \text{Current fall time} \end{array}$		Turn-off delay time	$V_{cc} = 390 \text{ V}, I_{C} = 5 \text{ A},$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V},$ Figure 17	-	100 160 205	-	ns ns ns
	$t_{r}(V_{off})$ $t_{d}(_{off})$ t_{f}	Off voltage rise time Turn-off delay time Current fall time	$V_{cc} = 390 \text{ V, } I_{C} = 5 \text{ A,}$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V,}$ $T_{J} = 125^{\circ}\text{C}$ Figure 17	-	165 250 310	-	ns ns ns

Symbol	Parameter	Test conditions	Min	Тур.	Max	Unit
E _{on} ⁽¹⁾ E _{off} ⁽²⁾ E _{ts}	Turn-on switching losses Turn-off switching losses Total switching losses	V_{CC} = 480 V, I_{C} = 5 A R_{G} = 10 Ω , V_{GE} = 15 V, Figure 15	1	60 340 400	-	μJ μJ μJ
Eon ⁽¹⁾ E _{off} ⁽²⁾ E _{ts}	Turn-on switching losses Turn-off switching losses Total switching losses	$V_{CC} = 480 \text{ V}, I_{C} = 5 \text{ A}$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V},$ $T_{J} = 125^{\circ}\text{C}$ Figure 15		90 540 630	-	μJ μJ μJ

Table 7. Switching energy (inductive load)

2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

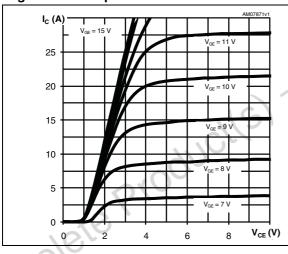


Figure 3. Transfer characteristics

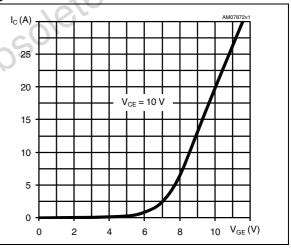
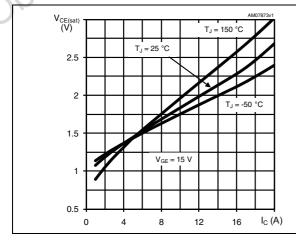
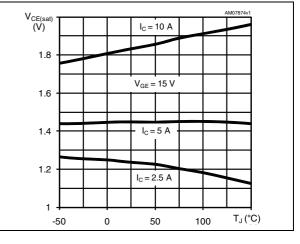


Figure 4. Collector-emitter on voltage vs. collector current

Figure 5. Collector-emitter on voltage vs. temperature

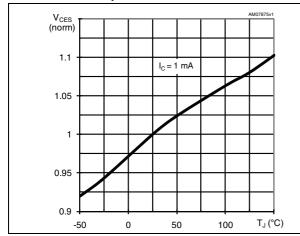




Eon is the turn-on losses when a typical diode is used in the test circuit in Figure 15. If the IGBT is offered
in a package with a co-pack diode, the co-pack diode is used as external diode. IGBTs and diode are at the
same temperature

^{2.} Turn-off losses included also include also the tail of the collector current

Figure 6. Normalized breakdown voltage vs. Figure 7. Normalized gate threshold voltage temperature vs. temperature



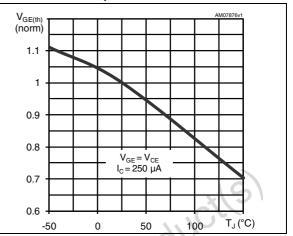
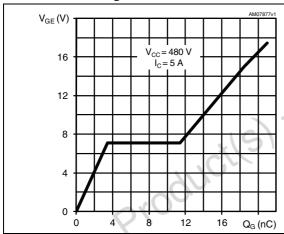


Figure 8. Gate charge vs. gate-emitter voltage

Figure 9. Capacitance variations



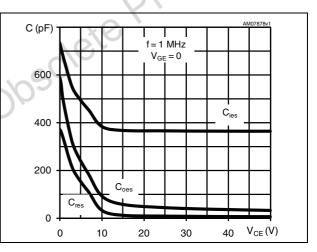
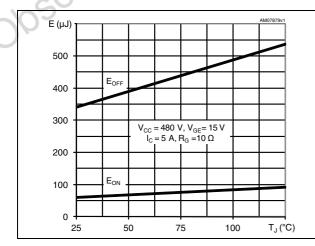
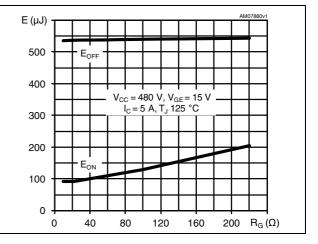


Figure 10. Switching losses vs. temperature

Figure 11. Switching losses vs. gate resistance

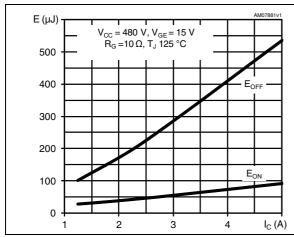




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Figure 12. Switching losses vs. collector current

Figure 13. Turn-off SOA



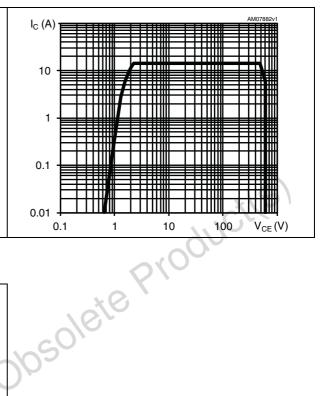
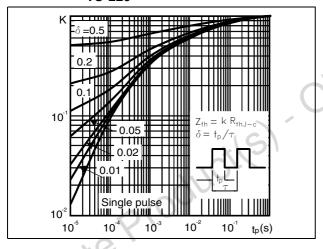


Figure 14. Thermal impedance for DPAK and TO-220



3 Test circuits

Figure 15. Test circuit for inductive load switching

Figure 16. Gate charge test circuit

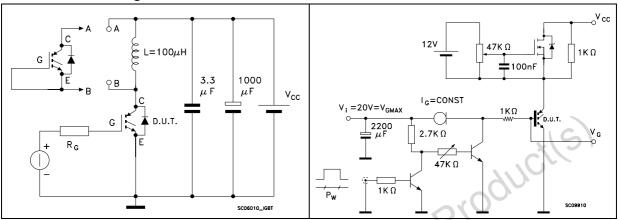
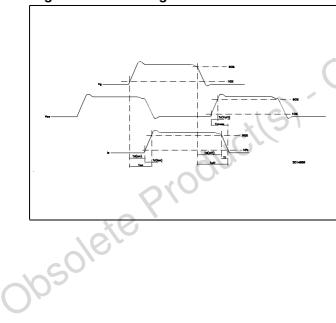


Figure 17. Switching waveforms



4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Obsolete Product(s). Obsolete Product(s)

Table 8. DPAK (TO-252) mechanical data

Dim.		mm			
Dim.	Min.	Тур.	Max.		
Α	2.20		2.40		
A1	0.90		1.10		
A2	0.03		0.23		
b	0.64		0.90		
b4	5.20		5.40		
С	0.45		0.60		
c2	0.48		0.60		
D	6.00		6.20		
D1		5.10	0,0		
Е	6.40	0	6.60		
E1		4.70			
е		2.28			
e1	4.40	60,	4.60		
Н	9.35	103	10.10		
L	1				
L1	16	2.80			
L2		0.80			
L4	0.60		1		
R	,00,	0.20			
V2	0°		8°		

Obsolete Product(s)

THERMAL PAD

E1

D1

R

GAUGE PLANE

12

L4

H

0068772_G

Figure 18. DPAK (TO-252) drawing

Table 9. TO-220 type A mechanical data

Dim.		mm	
	Min.	Тур.	Max.
А	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
С	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
е	2.40		2.70
e1	4.95		5.15
F	1.23	O.	1.32
H1	6.20	×0.	6.60
J1	2.40	16/	2.72
L	13	°CO,	14
L1	3.50	102	3.93
L20		16.40	
L30	16	28.90	
ØP	3.75		3.85
Q	2.65		2.95

Figure 19. TO-220 type A drawing

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-- *b* (Χ3)

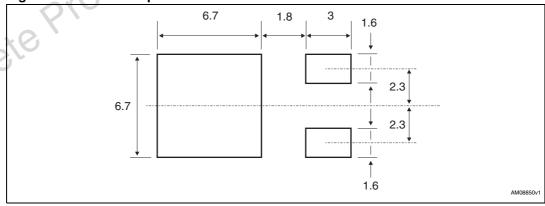
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5 Packaging mechanical data

Table 10. DPAK (TO-252) tape and reel mechanical data

Table 10. Dr Aix (10-202) tape and reel mechanical data						
	Таре			Reel		
Dim.	m	m	Dim.	m	m	
Dilli.	Min.	Max.	Dilli.	Min.	Max.	
A0	6.8	7	Α		330	
В0	10.4	10.6	В	1.5		
B1		12.1	С	12.8	13.2	
D	1.5	1.6	D	20.2	· · C/·	
D1	1.5		G	16.4	18.4	
Е	1.65	1.85	N	50		
F	7.4	7.6	Т		22.4	
K0	2.55	2.75	10	3,0		
P0	3.9	4.1	0//	Base qty.	2500	
P1	7.9	8.1	5	Bulk qty.	2500	
P2	1.9	2.1				
R	40					
Т	0.25	0.35				
W	15.7	16.3	1			

Figure 20. DPAK footprint^(a)



a. All dimension are in millimeters

10 pitches cumulative tolerance on tape +/- 0.2 mm Top cover B1 For machine ref. only A0 D1 P1 including draft and radii concentric around B0 User direction of feed Bending radius Obsolete Product User direction of feed AM08852v1

Figure 21. Tape for DPAK (TO-252)

5//

REEL DIMENSIONS 40mm min. Access hole At sl ot location В D С Tape slot in core for G measured at hub Full radius tape start 25 mm min. width Obsolete Product(s). Ob AM08851v2

Figure 22. Reel for DPAK (TO-252)

6 Revision history

Table 11. Document revision history

Date	Revision	Changes
06-Jul-2009	1	Initial release
17-Dec-2010	2	Inserted Section 2.1: Electrical characteristics (curves) on page 5

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